QUAD DIFFERENTIAL PCI-EXPRESS GEN1 CLOCK SOURCE ICS557-05A

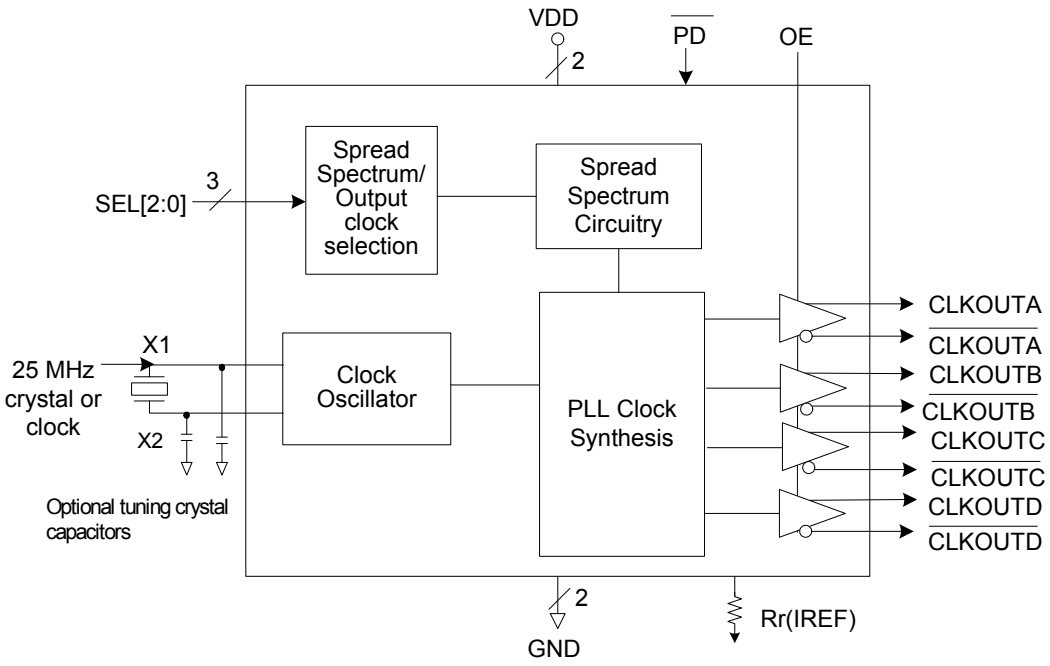
Description

The ICS557-05A is a spread-spectrum clock generator that supports PCI-Express requirements. It is used in PC or embedded systems to substantially reduce electro-magnetic interference (EMI). The device provides four differential HCSL or LVDS high-frequency outputs with spread spectrum capability. The output frequency and spread type are selectable using external pins.

Features

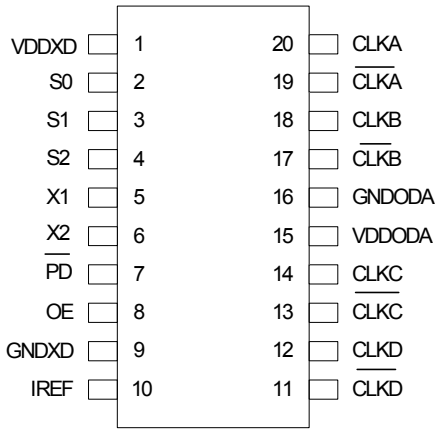
- Packaged in 20-pin TSSOP
- RoHS 5 (green) or RoHS 6 (green and lead free) complaint package
- Supports PCI-Express applications
- Four differential spread spectrum clock outputs
- Spread spectrum for EMI reduction
- Uses external 25 MHz clock or crystal input
- Power down pin turns off chip
- OE control tri-states outputs
- Spread and frequency selection via external pins
- Spread Bypass option available
- Industrial temperature range available
- **For PCIe Gen2 applications, see the 5V41066**
- **For PCIe Gen3 applications, see the 5V41236**

Block Diagram



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Pin Assignment



20-pin (173 mil) TSSOP

Spread Spectrum Selection Table

S2	S1	S0	Spread%	Spread Type	Output Frequency
0	0	0	-0.5	Down	100
0	0	1	-1.0	Down	100
0	1	0	-1.5	Down	100
0	1	1	No Spread	Not Applicable	100
1	0	0	-0.5	Down	200
1	0	1	-1.0	Down	200
1	1	0	-1.5	Down	200
1	1	1	No Spread	Not Applicable	200

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Pin Descriptions

Pin	Pin Name	Pin Type	Pin Description
1	VDDXD	Power	Connect to +3.3 V digital supply.
2	S0	Input	Spread spectrum select pin #0. See table above. Internal pull-up resistor.
3	S1	Input	Spread spectrum select pin #1. See table above Internal pull-up resistor.
4	S2	Input	Spread spectrum select pin #2. See table above. Internal pull-up resistor.
5	X1	Input	Crystal connection. Connect to a fundamental mode crystal or clock input.
6	X2	Output	Crystal connection. Connect to a fundamental mode crystal or leave open.
7	PD	Input	Powers down all PLL's and tri-states outputs when low. Internal pull-up resistor.
8	OE	Input	Provides output on, tri-states output (High = enable outputs; Low = disable outputs). Internal pull-up resistor.
9	GND	Power	Connect to digital ground.
10	IREF	Output	Precision resistor attached to this pin is connected to the internal current reference.
11	CLKD	Output	Selectable 100/200 MHz spread spectrum differential Compliment output clock D.
12	CLKD	Output	Selectable 100/200 MHz spread spectrum differential True output clock D.
13	CLKC	Output	Selectable 100/200 MHz spread spectrum differential Compliment output clock C.
14	CLKC	Output	Selectable 100/200 MHz spread spectrum differential True output clock C.
15	VDDODA	Power	Connect to +3.3 V analog supply.
16	GND	Power	Connect to analog ground.
17	CLKB	Output	Selectable 100/200 MHz spread spectrum differential Compliment output clock B.
18	CLKB	Output	Selectable 100/200 MHz spread spectrum differential True output clock B.
19	CLKA	Output	Selectable 100/200 MHz spread spectrum differential Compliment output clock A.
20	CLKA	Output	Selectable 100/200 MHz spread spectrum differential True output clock A.

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Application Information

Decoupling Capacitors

As with any high-performance mixed-signal IC, the ICS557-05A must be isolated from system power supply noise to perform optimally.

Decoupling capacitors of 0.01µF must be connected between each VDD and the PCB ground plane.

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

Each 0.01µF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

2) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (the ferrite bead and bulk decoupling capacitor can be mounted on the back). Other signal traces should be routed away from the ICS557-05A.

This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

External Components

A minimum number of external components are required for proper operation. Decoupling capacitors of 0.01 µF should be connected between VDD and GND pairs (1,9 and 15,16) as close to the device as possible.

On chip capacitors- Crystal capacitors should be connected from pins X1 to ground and X2 to ground to optimize the initial accuracy. The value (in pf) of these crystal caps equal (C_L-12)*2 in this equation, C_L=crystal load capacitance in pf. For example, for a crystal with a 16 pF load cap, each external crystal cap would be 8 pF. [(16-12)x2]=8.

Current Reference Source R_r (Iref)

If board target trace impedance (Z) is 50Ω, then Rr = 475Ω (1%), providing IREF of 2.32 mA, output current (I_{OH}) is equal to 6*IREF.

Load Resistors R_L

Since the clock outputs are open source outputs, 50 ohm external resistors to ground are to be connected at each clock output.

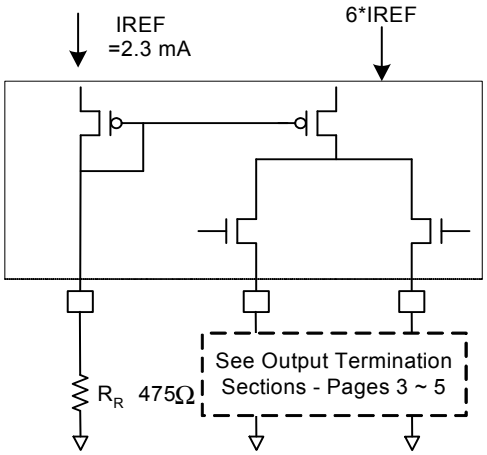
Output Termination

The PCI-Express differential clock outputs of the ICS557-05A are open source drivers and require an external series resistor and a resistor to ground. These resistor values and their allowable locations are shown in detail in the **PCI-Express Layout Guidelines** section.

The ICS557-05A can also be configured for LVDS compatible voltage levels. See the **LVDS Compatible Layout Guidelines** section.

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Output Structures



General PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1. Each 0.01µF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible.

2. No vias should be used between decoupling capacitor and VDD pin.

3. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

4. An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (any ferrite beads and bulk decoupling capacitors can be mounted on the back). Other signal traces should be routed away from the ICS557-05A.This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

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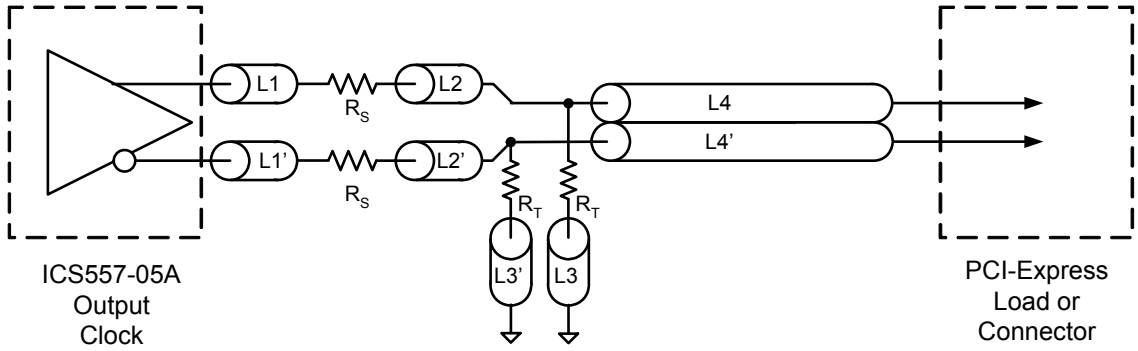
PCI-Express Layout Guidelines

Common Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, Route as non-coupled 50 ohm trace.	0.5 max	inch
L2 length, Route as non-coupled 50 ohm trace.	0.2 max	inch
L3 length, Route as non-coupled 50 ohm trace.	0.2 max	inch
R_S	33	ohm
R_T	49.9	ohm

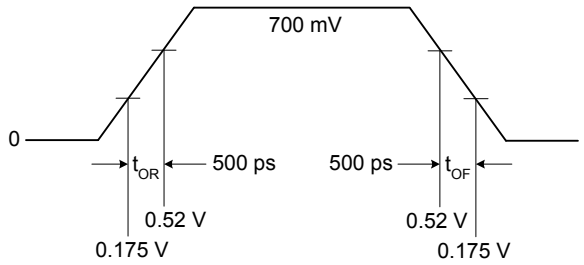
Differential Routing on a Single PCB	Dimension or Value	Unit
L4 length, Route as coupled **microstrip** 100 ohm differential trace.	2 min to 16 max	inch
L4 length, Route as coupled **stripline** 100 ohm differential trace.	1.8 min to 14.4 max	inch

Differential Routing to a PCI Express Connector	Dimension or Value	Unit
L4 length, Route as coupled **microstrip** 100 ohm differential trace.	0.25 to 14 max	inch
L4 length, Route as coupled **stripline** 100 ohm differential trace.	0.225 min to 12.6 max	inch

PCI-Express Device Routing



Typical PCI-Express (HCSL) Waveform



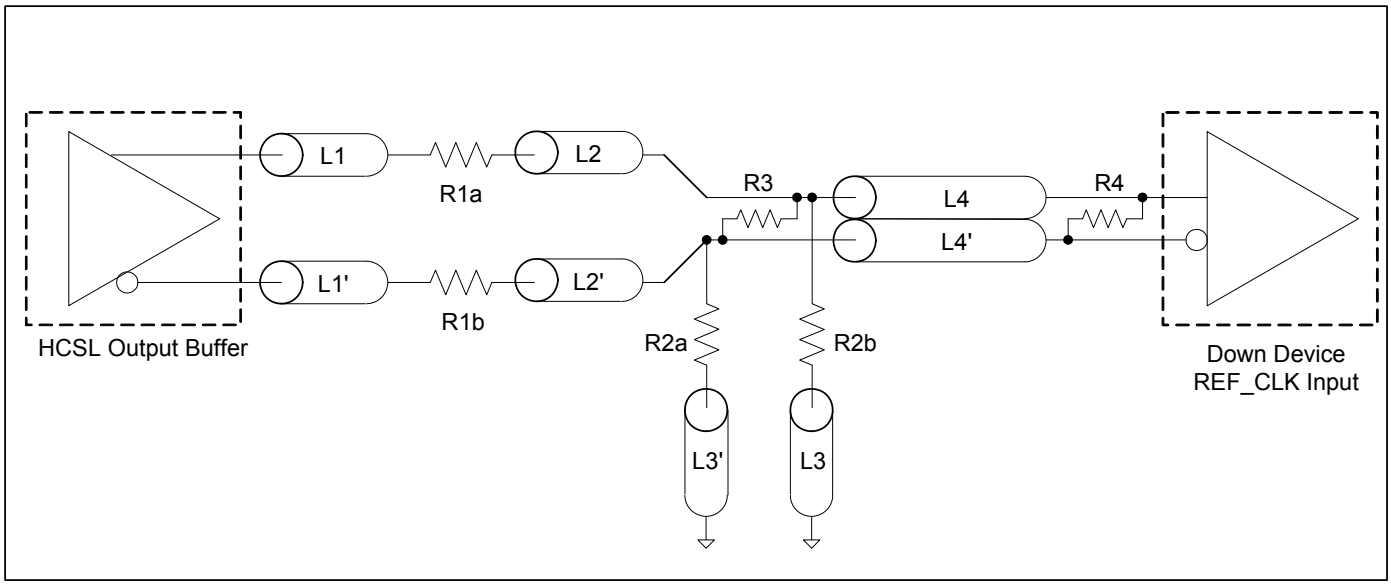
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LVDS Compatible Layout Guidelines

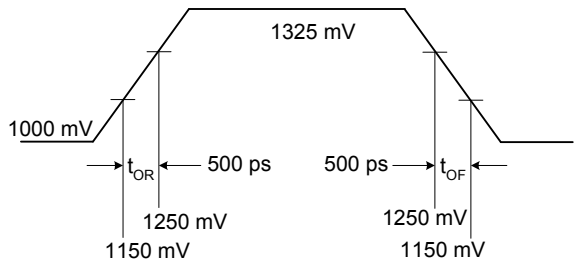
Alternative Termination for LVDS and other Common Differential Signals							
Vdiff	Vp-p	Vcm	R1	R2	R3	R4	Note
0.45v	0.22v	1.08	33	150	100	100	
0.58	0.28	0.6	33	78.7	137	100	
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible
0.60	0.3	1.2	33	174	140	100	Standard LVDS

R1a = R1b = R1
R2a = R2b = R2

LVDS Device Routing



Typical LVDS Waveform



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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS557-05A. These ratings are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD, VDDA	5.5 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature (commercial)	0 to +70° C
Ambient Operating Temperature (industrial)	-40 to +85° C
Storage Temperature	-65 to +150° C
Junction Temperature	125° C
Soldering Temperature	260° C
ESD Protection (Input)	2000 V min. (HBM)

DC Electrical Characteristics

Unless stated otherwise, **VDD = 3.3 V ±5%**, Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Supply Voltage	V		3.135		3.465	
Input High Voltage[1]	V_{IH}		2.0		VDD +0.3	V
Input Low Voltage[1]	V_{IL}		VSS-0.3		0.8	V
Input Leakage Current[2]	I_{IL}	0 < Vin < VDD	-5		5	µA
Operating Supply Current	I_{DD}	50Ω, 2 pF load @100 MHz		105		mA
	I_{DDOE}	OE =Low		40		mA
	I_{DDPD}	No load, $\overline{PD}$ =Low		500		µA
Input Capacitance	C_{IN}	Input pin capacitance			7	pF
Output Capacitance	C_{OUT}	Output pin capacitance			6	pF
Pin Inductance	L_{PIN}				5	nH
Output Resistance	Rout	CLK outputs	3.0			kΩ
Pull-up Resistance	R_{PUP}	OE, SEL, $\overline{PD}$ pins		110		kΩ

1. Single edge is monotonic when transitioning through region.
2. Inputs with pull-ups/-downs are not included.

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AC Electrical Characteristics - CLKOUT, HCSL

Unless stated otherwise, **VDD=3.3 V ±5%**, Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Frequency				25		MHz
Output Frequency		HCSL termination			200	MHz
Output High Voltage[1,2]	V_{OH}		660	700	850	mV
Output Low Voltage[1,2]	V_{OL}		-150	0	27	mV
Crossing Point Voltage[1,2]		Absolute	250	350	550	mV
Crossing Point Voltage[1,2,4]		Variation over all edges			140	mV
Jitter, Cycle-to-Cycle[1,3]					80	ps
Modulation Frequency		Spread spectrum	30	31.5	33	kHz
Rise Time[1,2]	t_{OR}	From 0.175 V to 0.525 V	175	332	700	ps
Fall Time[1,2]	t_{OF}	From 0.525 V to 0.175 V	175	344	700	ps
Skew between outputs		At crossing point Voltage			50	ps
Duty Cycle[1,3]			45		55	%
Output Enable Time[5]		All outputs			10	us
Output Disable Time[5]		All outputs			10	us
Power-up Time	t_{STABLE}	From power-up VDD=3.3 V		3.0		ms
Spread Change Time	t_{SPREAD}	Settling period after spread change		3.0		ms

[1] Test setup is R_L=50 ohms with 2 pF, Rr = 475Ω (1%).

[2] Measurement taken from a single-ended waveform.

[3] Measurement taken from a differential waveform.

[4] Measured at the crossing point where instantaneous voltages of both CLKOUT and $\overline{\text{CLKOUT}}$ are equal.

[5] CLKOUT pins are tri-stated when OE is asserted low. CLKOUT is driven differential when OE is high unless its $\overline{\text{PD}}$= low.

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AC Electrical Characteristics - CLKOUT, LVDS

Unless stated otherwise, **VDD=3.3 V ±5%**, Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Frequency				25		MHz
Output Frequency		LVDS termination			100	MHz
Differential Output Voltage	V_{OD}		247		454	mV
Offset Voltage	V_{OS}		1.125		1.375	V
ΔV_{OD}		|Change to V_{OD}|			50	mV
ΔV_{OS}		|Change to V_{OS}|			50	mV
Jitter, Cycle-to-Cycle[1,3]					80	ps
Modulation Frequency		Spread spectrum	30	31.5	33	kHz
Slew Rate, Rise[1,3]	t_{SLR}	Measured from ±150 mV from crossing point voltage	1		4	V/ns
Slew Rate, Fall[1,3]	t_{SLF}	Measured from ±150 mV from crossing point voltage	1		4	V/ns
Skew between outputs		At crossing point Voltage			50	ps
Duty Cycle[1,3]			45		55	%
Output Enable Time[5]		All outputs			10	µs
Output Disable Time[5]		All outputs			10	µs
Power-up Time	t_{STABLE}	From power-up VDD=3.3 V		3		ms
Spread Change Time	t_{SPREAD}	Settling period after spread change		3		ms

[1] Test setup is R_L=50 ohms with 2 pF, Rr = 475Ω (1%).

[2] Measurement taken from a single-ended waveform.

[3] Measurement taken from a differential waveform.

[4] Measured at the crossing point where instantaneous voltages of both CLKOUT and $\overline{\text{CLKOUT}}$ are equal.

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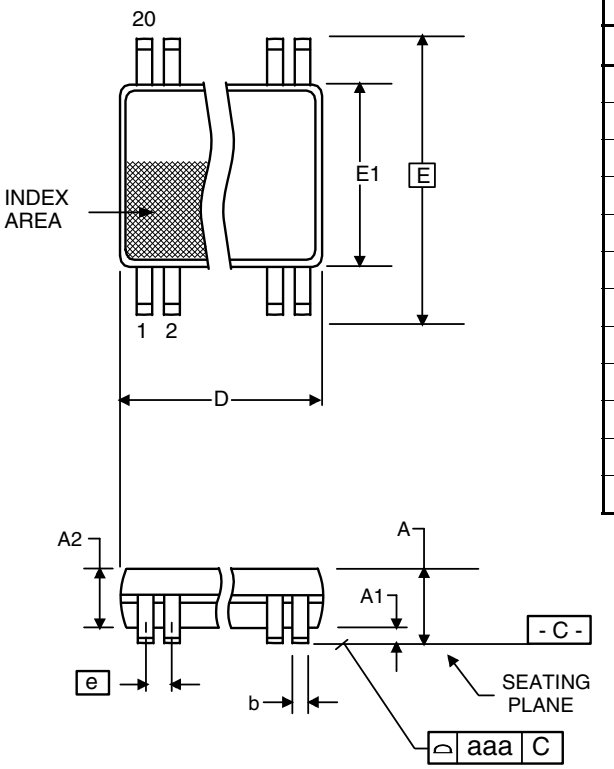
Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		93		°C/W
	θ_{JA}	1 m/s air flow		78		°C/W
	θ_{JA}	3 m/s air flow		65		°C/W
Thermal Resistance Junction to Case	θ_{JC}			20		°C/W

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Package Outline and Package Dimensions (20-pin TSSOP, 173 mil Body)

Package dimensions are kept current with JEDEC Publication No. 95, MO-153



	Millimeters		Inches*	
Symbol	**Min**	**Max**	**Min**	**Max**
A		1.20		0.047
A1	0.05	0.15	0.002	0.006
A2	0.80	1.05	0.032	0.041
b	0.19	0.30	0.007	0.012
c	0.09	0.20	0.0035	0.008
D	6.40	6.60	0.252	0.260
E	6.40 BASIC		0.252 BASIC	
E1	4.30	4.50	0.169	0.177
e	0.65 Basic		0.0256 Basic	
L	0.45	0.75	0.018	0.030
a	0°	8°	0°	8°
aaa	--	0.10	--	0.004

Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
557G-05ALF	557G-05ALF	Tubes	20-pin TSSOP	0 to +70° C
557G-05ALFT	557G-05ALF	Tape and Reel	20-pin TSSOP	0 to +70° C
557GI-05ALF	557GI-05AL	Tubes	20-pin TSSOP	-40 to +85° C
557GI-05ALFT	557GI-05AL	Tape and Reel	20-pin TSSOP	-40 to +85° C

"LF" suffix to the part number are the Pb-Free configuration, RoHS compliant.

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